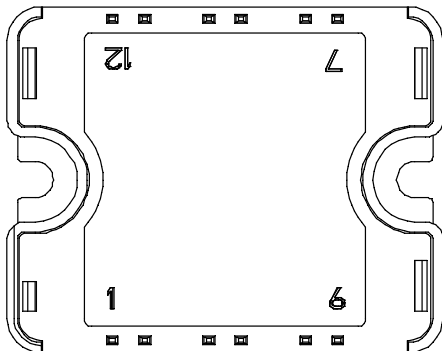
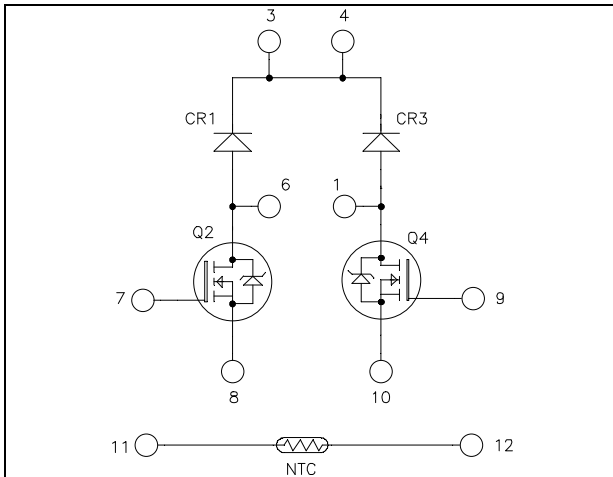


**Dual boost chopper  
Super Junction MOSFET  
Power Module**

**$V_{DSS} = 600V$**   
 **$R_{DSon} = 70m\Omega \text{ max @ } T_j = 25^\circ C$**   
 **$I_D = 39A \text{ @ } T_c = 25^\circ C$**



Pins 3/4 must be shorted together

### Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

### Features



- Ultra low  $R_{DSon}$
  - Low Miller capacitance
  - Ultra low gate charge
  - Avalanche energy rated
  - Very rugged
  - Very low stray inductance
    - Symmetrical design
  - Internal thermistor for temperature monitoring
  - High level of integration
- ### Benefits
- Outstanding performance at high frequency operation
  - Direct mounting to heatsink (isolated package)
  - Low junction to case thermal resistance
  - Solderable terminals both for power and signal for easy PCB mounting
  - Each leg can be easily paralleled to achieve a single boost of twice the current capability
  - Low profile
  - RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	600	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	39
		$T_c = 80^\circ C$	29
$I_{DM}$	Pulsed Drain current	160	A
$V_{GS}$	Gate - Source Voltage	$\pm 20$	V
$R_{DSon}$	Drain - Source ON Resistance	70	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	250
$I_{AR}$	Avalanche current (repetitive and non repetitive)	20	A
$E_{AR}$	Repetitive Avalanche Energy	1	mJ
$E_{AS}$	Single Pulse Avalanche Energy	1800	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$			25	$\mu\text{A}$
		$T_j = 25^\circ\text{C}$				
		$V_{GS} = 0V, V_{DS} = 600V$			250	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$			70	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2.7\text{mA}$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	$\text{nA}$

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		7		$\text{nF}$
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		2.56		
$C_{rss}$	Reverse Transfer Capacitance	$f = 1\text{MHz}$		0.21		
$Q_g$	Total gate Charge	$V_{GS} = 10V$		259		$\text{nC}$
$Q_{gs}$	Gate – Source Charge	$V_{Bus} = 300V$		29		
$Q_{gd}$	Gate – Drain Charge	$I_D = 39A$		111		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive Switching @ 125°C</b> $V_{GS} = 15V$ $V_{Bus} = 400V$ $I_D = 39A$ $R_G = 5\Omega$		21		$\text{ns}$
$T_r$	Rise Time			30		
$T_{d(off)}$	Turn-off Delay Time			283		
$T_f$	Fall Time			84		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 15V, V_{Bus} = 400V$ $I_D = 39A, R_G = 5\Omega$		670		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			980		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 15V, V_{Bus} = 400V$ $I_D = 39A, R_G = 5\Omega$		1096		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			1206		

**Chopper diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		600			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 600V$	$T_j = 25^\circ\text{C}$		25	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$		500	
$I_F$	DC Forward Current	$T_c = 80^\circ\text{C}$		30		A
$V_F$	Diode Forward Voltage	$I_F = 30A$		1.8	2.2	V
		$I_F = 60A$		2.2		
		$I_F = 30A$	$T_j = 125^\circ\text{C}$		1.5	
$t_{rr}$	Reverse Recovery Time	$I_F = 30A$ $V_R = 400V$ $di/dt = 200A/\mu\text{s}$	$T_j = 25^\circ\text{C}$		25	$\text{ns}$
			$T_j = 125^\circ\text{C}$		160	
$Q_{rr}$	Reverse Recovery Charge	$I_F = 30A$ $V_R = 400V$ $di/dt = 200A/\mu\text{s}$	$T_j = 25^\circ\text{C}$		35	$\text{nC}$
			$T_j = 125^\circ\text{C}$		480	

**Thermal and package characteristics**

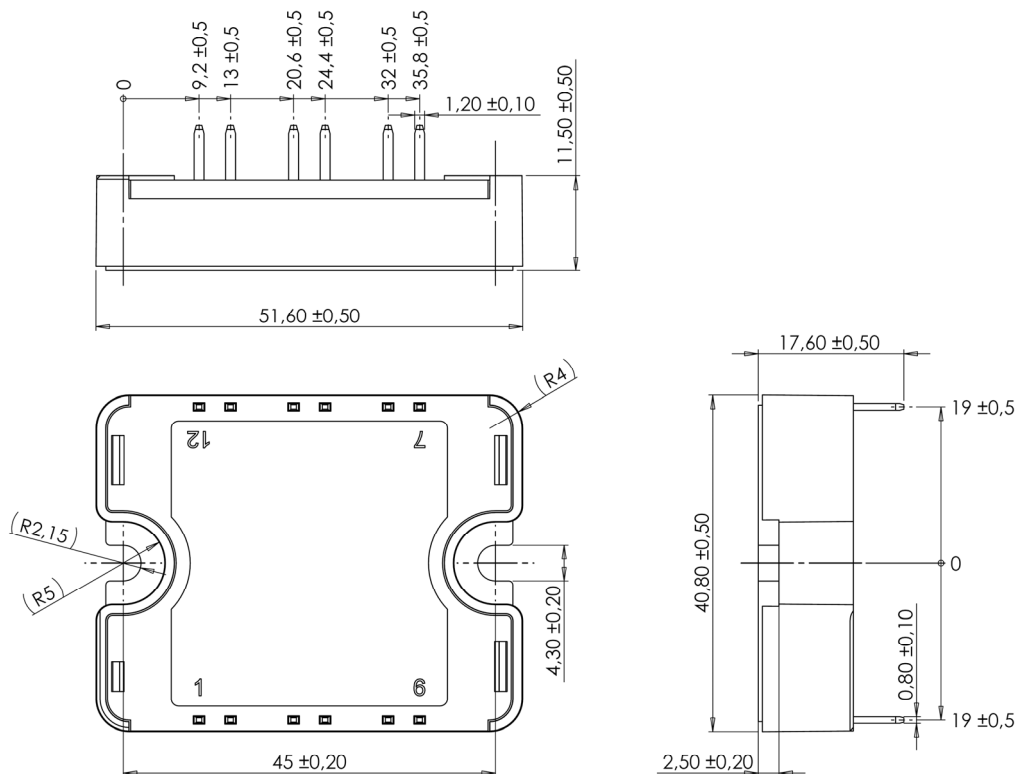
Symbol	Characteristic	Min	Typ	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance	CoolMOS		0.5	°C/W	
		Diode		1.2		
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000			V	
T <sub>J</sub>	Operating junction temperature range	-40		150	°C	
T <sub>STG</sub>	Storage Temperature Range	-40		125		
T <sub>C</sub>	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				80	g

**Temperature sensor NTC** (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
ΔR <sub>25</sub> /R <sub>25</sub>			5		%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K		3952		K
ΔB/B	T <sub>C</sub> = 100°C		4		%

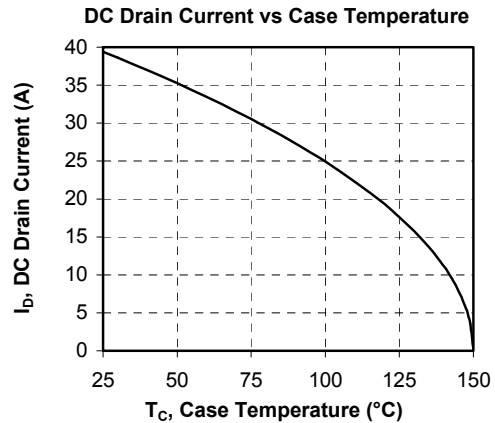
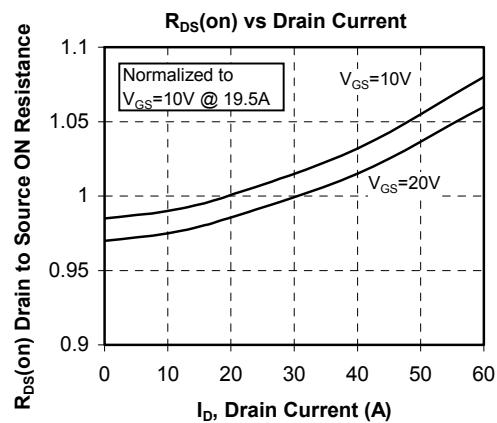
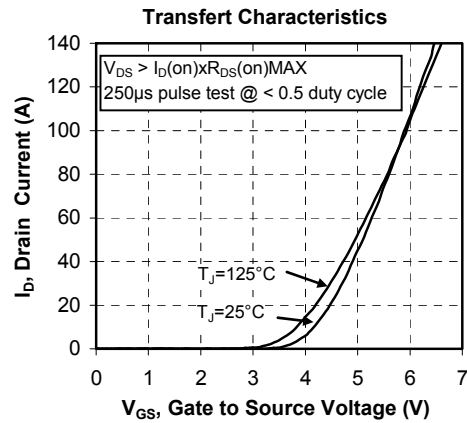
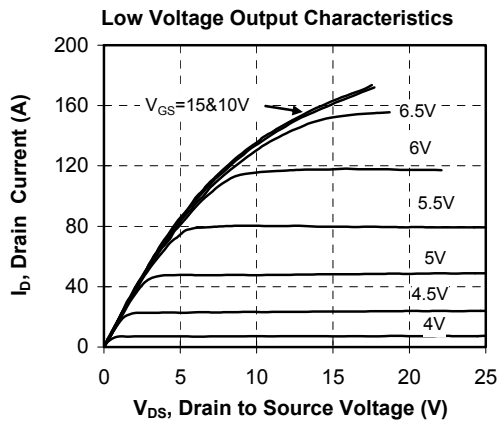
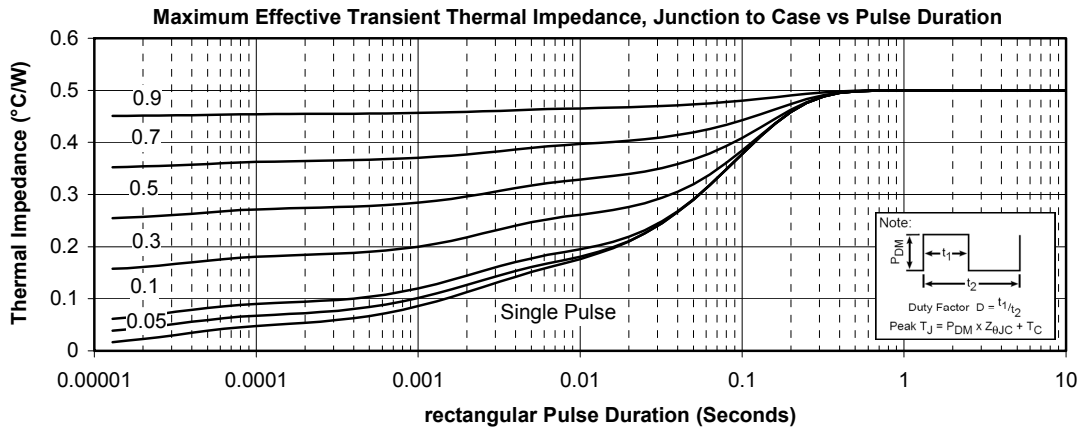
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

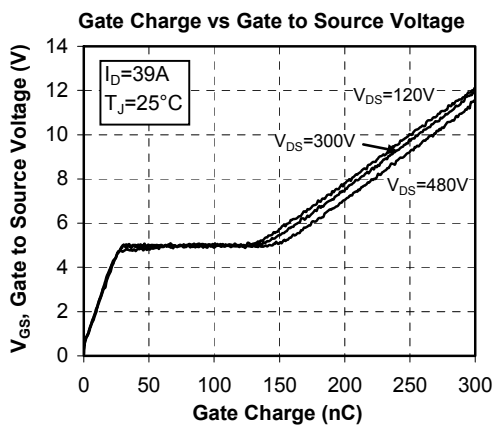
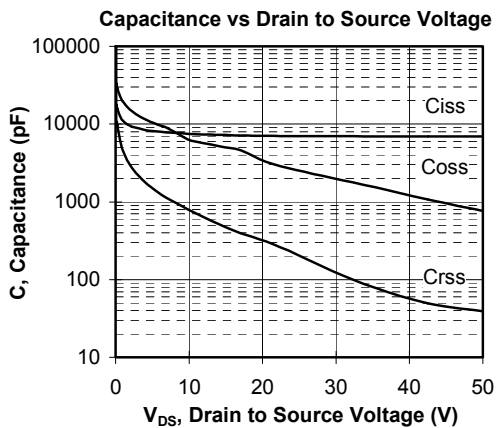
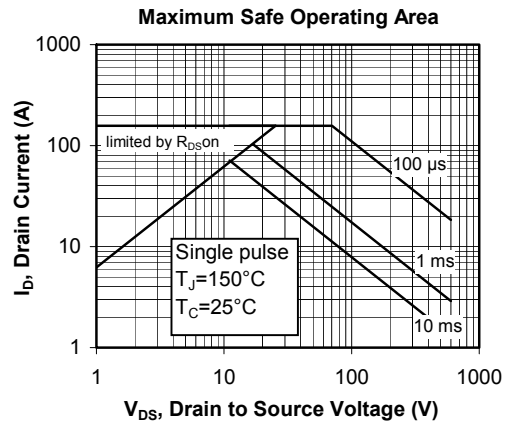
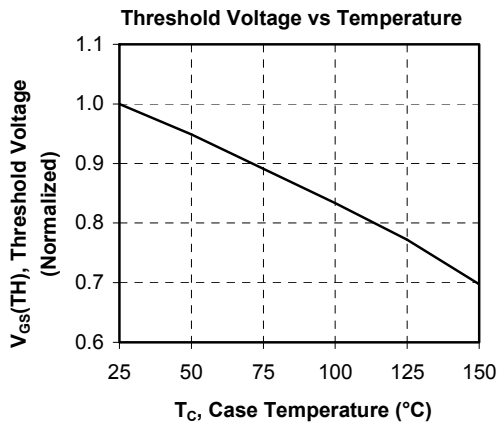
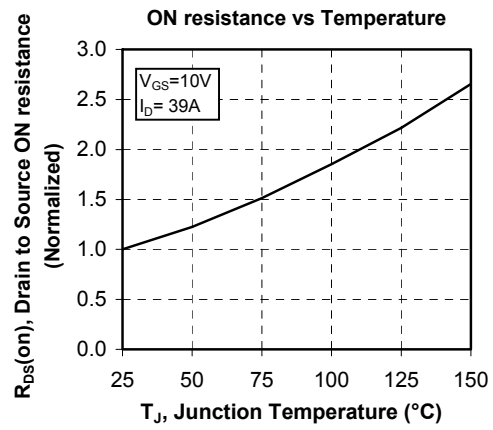
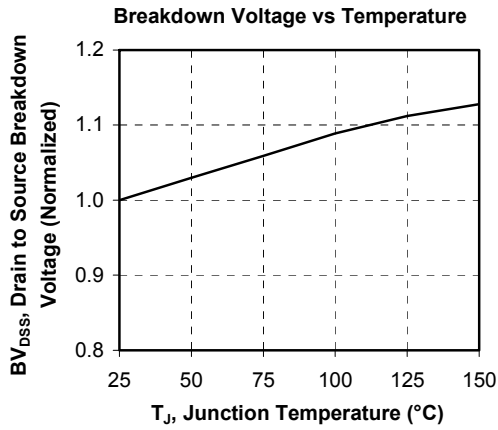
T: Thermistor temperature  
 R<sub>T</sub>: Thermistor value at T

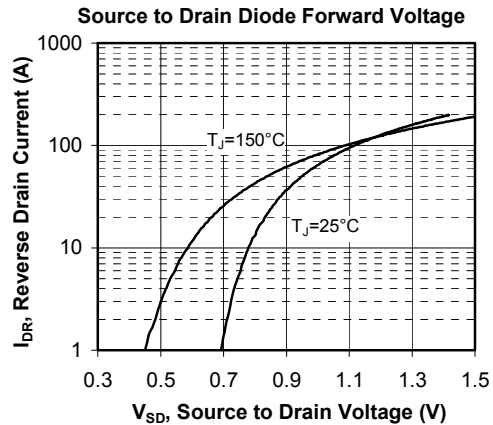
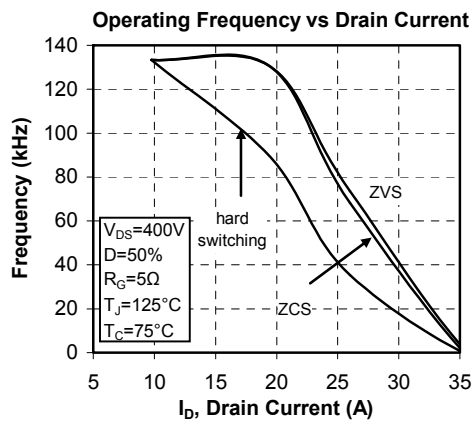
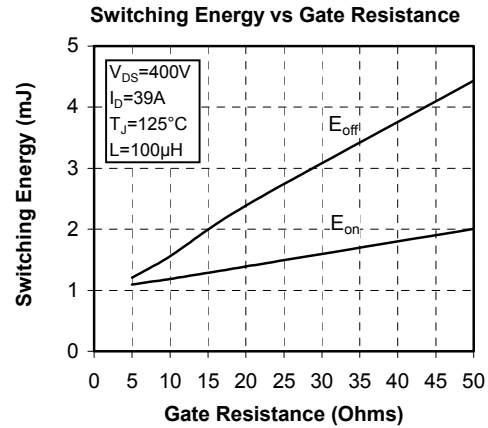
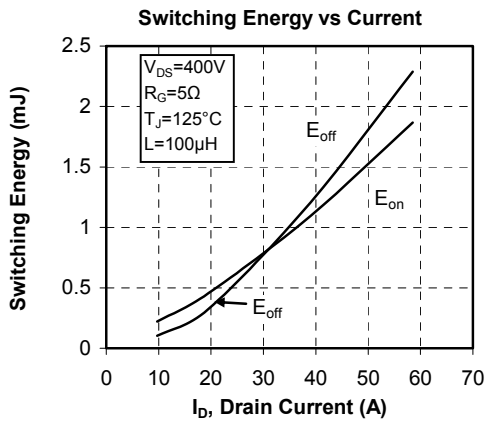
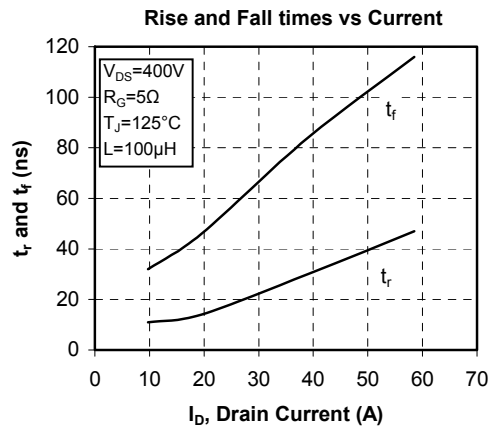
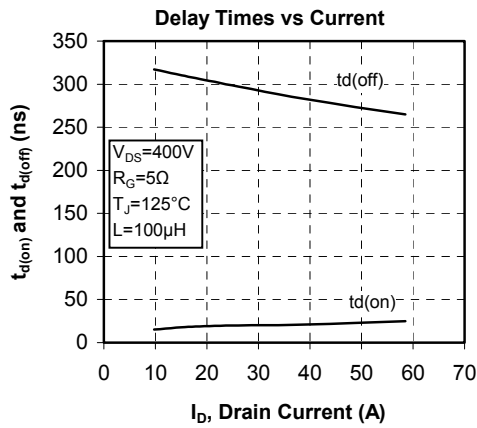
**SP1 Package outline** (dimensions in mm)


See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

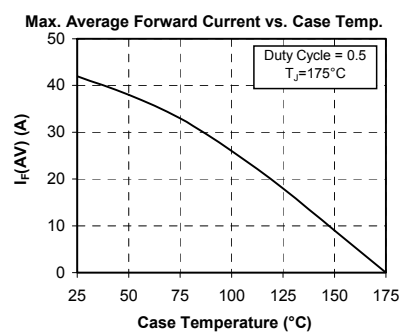
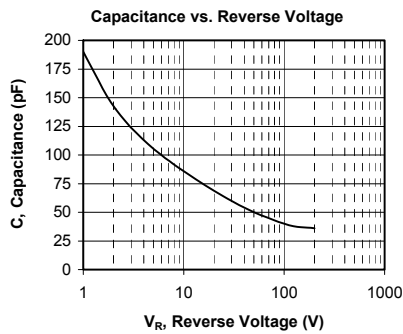
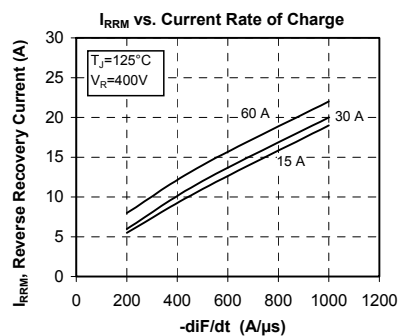
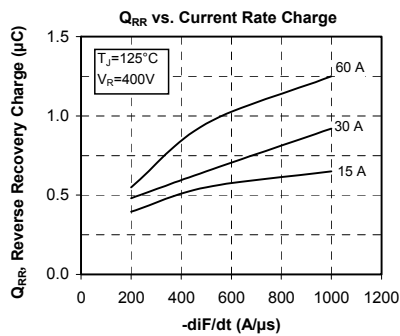
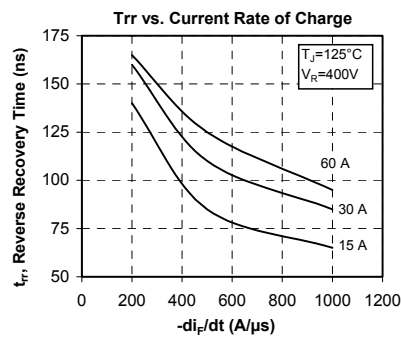
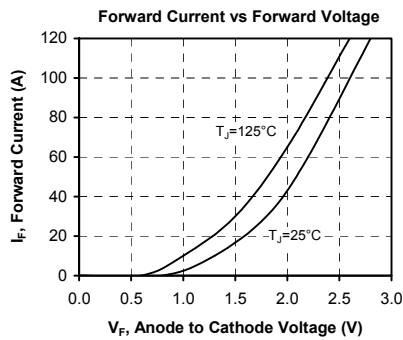
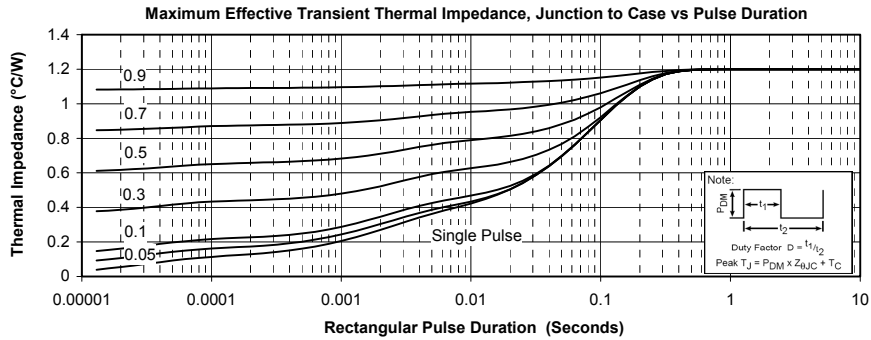
## Typical CoolMOS Performance Curve







## Typical chopper diode Performance Curve



“COOLMOS™” comprise a new family of transistors developed by Infineon Technologies AG. “COOLMOS” is a trademark of Infineon Technologies AG”.

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